## Product Specification

## PE42721

## UltraCMOS ${ }^{\circledR}$ SPDT RF Switch 5-2200 MHz

## Product Description

The PE42721 is a HaRPTM technology-enhanced absorptive $75 \Omega$ SPDT RF switch developed on the UltraCMOS ${ }^{\circledR}$ process technology.

PE42721 is a highly linear device delivering high isolation and very low insertion loss performance. It is designed for broadband applications such as TV tuner modules, CATV signal switching and distribution, DTV, multi-tuner digital video recorders (DVRs) and set-top boxes.

PE42721 supports +1.8 V control logic and offers high ESD protection. PE42721 is pin compatible to PE42750. In addition, no blocking capacitors are required if DC voltage is not present on the RF ports.

Peregrine's HaRP™ technology enhancement is an innovative feature of the UltraCMOS ${ }^{\circledR}$ process, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram


## Features

- HaRP ${ }^{\text {™ }}$ technology enhanced
- High linearity
- CTB of -99 dBc
- CSO better than -105 dBc
- Supports +1.8 V control logic
- Low insertion loss
- 0.40 dB @ 220 MHz
- 0.50 dB @ 870 MHz
- 0.65 dB @ 2200 MHz
- High isolation
- 85 dB @ 220 MHz
- 68 dB @ 870 MHz
- 53 dB @ 2200 MHz
- ESD performance
- $3 k V$ HBM on RF pins to GND
- 2 kV HBM on all other pins
- 1 kV CDM on all pins

Figure 2. Package Type 12-lead 3x3 mm QFN


Table 1. Electrical Specifications Temp $=+\mathbf{2 5}^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}\left(\mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{L}}=75 \Omega\right)$

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Operational frequency |  |  | 5 |  | 2200 | MHz |
| Insertion loss | RFC-RFX | $5-220 \mathrm{MHz}$ |  | 0.40 | 0.55 | dB |
|  |  | 221-870 MHz |  | 0.50 | 0.70 | dB |
|  |  | 871-2200 MHz |  | 0.65 | 0.85 | dB |
| Isolation | RFX-RFX | $5-220 \mathrm{MHz}$ | 81 | 85 |  | dB |
|  |  | $221-870 \mathrm{MHz}$ | 65 | 68 |  | dB |
|  |  | $871-2200 \mathrm{MHz}$ | 52 | 53 |  | dB |
| Isolation | RFC-RFX | $5-220 \mathrm{MHz}$ | 68 | 70 |  | dB |
|  |  | $221-870 \mathrm{MHz}$ | 57 | 59 |  | dB |
|  |  | 871-2200 MHz | 53 | 55 |  | dB |
| Return loss | All ports | 870 MHz |  | 18 |  | dB |
|  |  | 2200 MHz |  | 15 |  | dB |
| Input 0.1 dB compression ${ }^{1,2}$ | RFC-RFX | $45-1000 \mathrm{MHz}$ |  | 27 |  | dBm |
| IIP2 ${ }^{3}$ | RFX | $45-2200 \mathrm{MHz}$ |  | 110 |  | dBm |
| IIP3 | RFX | 5-2200 MHz |  | 60 |  | dBm |
| СТВ |  | 159 channels; 42 dBmV per channel output power |  | -99 |  | dBc |
| CSO |  | 159 channels; 42 dBmV per channel output power |  | <-105 |  | dBc |
| Cross modulation distortion |  | 159 channels; 42 dBmV per channel output power |  | -89.5 |  | dBc |
| Video feedthrough |  | DC measurement |  | 4 |  | mV PP |
| Switching time |  | $50 \%$ CTRL to $90 \%$ or $10 \%$ RF |  | 1 | 1.5 | $\mu \mathrm{s}$ |

Notes: 1. The input 0.1 dB compression point $(\mathrm{P} 0.1 \mathrm{~dB})$ is a linearity figure of merit. Refer to Table 3 for the RF input power $\mathrm{P}_{\mathrm{IN}}$ 2. $\mathrm{P} 0.1 \mathrm{~dB}=25 \mathrm{dBm} @ 2.2 \mathrm{GHz}$
3. IIP2 = 83 dBm @ 5 MHz

Figure 3. Pin Configuration (Top View)


Table 2. Pin Descriptions

| Pin \# | Pin Name | Description |
| :---: | :---: | :--- |
| 1 | GND | RF Ground |
| 2 | RF1 $^{1}$ | RF Port 1 |
| 3 | GND | RF Ground |
| 4 | GND | RF Ground |
| 5 | RFC $^{1}$ | RF Common |
| 6 | GND | RF Ground |
| 7 | GND | RF Ground |
| 8 | RF2 |  |
| 9 | GND | RF Ground |
| 10 | CTRL2 | Digital control logic input 2 |
| 11 | CTRL1 | Digital control logic input 1 |
| 12 | VDD | Supply Voltage |
| Pad | GND | Exposed pad: Ground for proper operation |

Note 1: RF pins 2, 5, and 8 must be at OV DC. The RF pins do not require DC blocking capacitors for proper operation if the OV DC requirement is met

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Table 3. Operating Ranges

| Parameter | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{DD}}$ | 2.3 | 3.3 | 5.5 | V |
| Supply current | IDD |  | 110 | 200 | $\mu \mathrm{A}$ |
| Digital input high (CTRL1, CTRL2) | $\mathrm{V}_{\text {IH }}$ | 1.17 |  | 3.6 | V |
| Digital input low (CTRL1, CTRL2) | VIL | -0.3 |  | 0.6 | V |
| Digital input current | $\mathrm{I}_{\text {ctri }}$ |  |  | 1 | $\mu \mathrm{A}$ |
| $\begin{array}{\|l} \begin{array}{l} \text { RF input power } \\ (\text { RFC-RFX })^{1} \\ 5 \end{array} \\ 5 \leq 45 \mathrm{MHz} \\ 45 \end{array}$ | Pin |  |  | $\begin{aligned} & 18 \\ & 22 \end{aligned}$ | dBm dBm |
| RF input power into terminated ports (RFX) ${ }^{1}$ $\begin{array}{r} 5 \leq 45 \mathrm{MHz} \\ 45 \leq 2200 \mathrm{MHz} \end{array}$ | $\mathrm{P}_{\text {in,term }}$ |  |  | $\begin{aligned} & 16 \\ & 16 \end{aligned}$ | dBm dBm |
| Operating temperature range | Top | -40 | +25 | +85 | ${ }^{\circ} \mathrm{C}$ |

Note 1: $100 \%$ duty cycle, all bands, $75 \Omega$
Table 4. Absolute Maximum Ratings

| Parameter/Condition | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $V_{D D}$ | -0.3 | 5.5 | V |
| Digital input voltage | $\mathrm{V}_{\text {ctRL }}$ | -0.3 | 3.6 | V |
| $\begin{array}{\|lr} \begin{array}{l} \text { RF input power } \\ \text { (RFC-RFX) } \end{array} \\ & 5 \leq 45 \mathrm{MHz} \\ & 45 \leq 2200 \mathrm{MHz} \end{array}$ | Pin |  | $\begin{aligned} & 18 \\ & 22 \end{aligned}$ | dBm dBm |
| RF input power into terminated ports (RFX) ${ }^{1}$ $\begin{array}{r} 5 \leq 45 \mathrm{MHz} \\ 45 \leq 2200 \mathrm{MHz} \end{array}$ | $\mathrm{P}_{\text {in,term }}$ |  | $\begin{aligned} & 16 \\ & 16 \end{aligned}$ | dBm dBm |
| Storage temperature range | $\mathrm{T}_{\text {st }}$ | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| ESD voltage $\mathrm{HBM}^{2}$ <br> RF pins to GND <br> All other pins | $\mathrm{V}_{\text {ESD,Hbм }}$ |  | $\begin{aligned} & 3000 \\ & 2000 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| ESD voltage $\mathrm{MM}^{3}$, all pins | $\mathrm{V}_{\text {ESD,MM }}$ |  | 100 | V |
| ESD Voltage CDM ${ }^{4}$, all pins | $\mathrm{V}_{\text {ESD,CDM }}$ |  | 1000 | V |

Notes: 1.100\% duty cycle, all bands, $75 \Omega$
2. Human Body Model (MIL-STD-883 Method 3015)
3. Machine Model (JEDEC JESD22-A115)
4. Charged Device Model (JEDEC JESD22-C101)

## Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS ${ }^{\circledR}$ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

## Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS ${ }^{\text {® }}$ devices are immune to latch-up.

## Switching Frequency

The PE42721 has a maximum 25 kHz switching rate.

Switching frequency describes the time duration between switching events. Switching time is the time duration between the point the control signal reaches $50 \%$ of the final value and the point the output signal reaches within $10 \%$ or $90 \%$ of its target value. Switching time is provided in Table 1.

Table 5. Truth Table ${ }^{1}$

| C1 | C2 | RFC - RF1 | RFC - RF2 |
| :---: | :---: | :---: | :---: |
| Low | Low | ON | OFF |
| Low | High | OFF | ON |
| High | Low | OFF | ON |
| High | High | ON | OFF |

Note 1: A versatile logic table has been established to allow either C1 or C2 to act as a single pin control and in either polarity

## Spurious Performance

The typical spurious performance of the PE42721 is -124 dBm .

## Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE42721 in the 12-lead $3 \times 3 \mathrm{~mm}$ QFN package is MSL1.

## Typical Performance Data @ $25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ unless otherwise specified

Figure 4. Insertion Loss (RFC-RFX)


Figure 5. Insertion Loss vs. Temp (RFC-RFX)


Figure 6. Insertion Loss vs. VDD (RFC-RFX)


## Typical Performance Data @ $25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ unless otherwise specified

Figure 7. RFC Port Return Loss vs. Temp (RF1 Active)


Figure 9. RFC Port Return Loss vs. Temp (RF2 Active)


Figure 8. RFC Port Return Loss vs. $\mathrm{V}_{\mathrm{DD}}$ (RF1 Active)


Figure 10. RFC Port Return Loss vs. $\mathrm{V}_{\mathrm{DD}}$ (RF2 Active)


## Typical Performance Data @ $25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ unless otherwise specified

Figure 11. Active Port Return Loss vs. Temp (RF1 Active)


Figure 13. Active Port Return Loss vs. Temp (RF2 Active)


Figure 12. Active Port Return Loss vs. $\mathrm{V}_{\mathrm{DD}}$ (RF1 Active)


Figure 14. Active Port Return Loss vs. $\mathrm{V}_{\mathrm{DD}}$ (RF2 Active)


## Typical Performance Data @ $25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ unless otherwise specified

Figure 15. Isolation vs. Temp (RFX-RFX)


Figure 17. Isolation vs. Temp (RFC-RFX)


Figure 16. Isolation vs. $V_{\text {DD }}$ (RFX-RFX)


Figure 18. Isolation vs. $\mathrm{V}_{\mathrm{DD}}$ (RFC-RFX)


## Evaluation Board

The SPDT switch evaluation board was designed to ease customer evaluation of Peregrine's PE42721. The RF common port is connected through a $75 \Omega$ transmission line via the F-Type connector, J2. RF1 and RF2 ports are connected through $75 \Omega$ transmission lines via F-Type connectors J 1 and J 3 , respectively. A $75 \Omega$ through transmission line is available via F-Type connectors J 4 and J 5 , which can be used to de-embed the loss of the PCB. J6 provides DC and digital inputs to the device.

Figure 19. Evaluation Board Layout


Figure 20. Evaluation Board Schematic


## NOTES:

1. USE 101-0491-01
2. CAUTION

CONTANS PARTS AND ASSEMBLES SUSCEPTIBLE
TO DAMAGE BYELECTROSTABC DSCCHARGE (ESD)
3. ALI TRANSMISKN LINES ARE:

12MI WDTH, 12MIL GAPS, 28MI CORE DIELECTRIC
4.3 ETAND 2.1MIL CU THCKNESS.

Figure 21. Package Drawing
12-lead $3 \times 3$ mm QFN


Figure 22. Top Marking Specifications


$$
\begin{aligned}
& =\text { Pin } 1 \text { designator } \\
\mathrm{YY} & =\text { Last two digits of assembly year } \\
\mathrm{WW} & =\text { Assembly work week } \\
\text { ZZZZZZ } & =\text { Assembly lot code (maximum six characters) }
\end{aligned}
$$

DOC-64916

Figure 23. Tape and Reel Drawing


NDTES:

1. 10 SPRACKET HOLE PITCH CUMMLATIVE TILERACE 00.2
2. LAMBR IN CLMPLIAME MITH EIA 481
3. PDCKE PISITITN 田ATIVE TD SPRCCKET HILE MEESLIRED

AS TAE PISIITIN GF PCCKET, NUI PCLKET HEE
Ao $=3.30 \pm 0.1 \mathrm{~mm}$
$\mathrm{Bo}=3.30 \pm 0.1 \mathrm{~mm}$
$\mathrm{Ko}=1.10 \pm 0.1 \mathrm{~mm}$


Device Orientation in Tape

Table 6. Ordering Information

| Order Code | Description | Package | Shipping Method |
| :---: | :---: | :---: | :---: |
| PE42721MLBA-Z | PE42721 SPDT RF switch | Green 12-lead 3x3 mm QFN | 3000 units/T\&R |
| EK42721-02 | PE42721 Evaluation kit | Evaluation kit | $1 / B o x$ |

## Sales Contact and Information

For sales and contact information please visit www.psemi.com.

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